NSN 5961-01-024-2135



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-024-2135 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -275.0 collector to base voltage/static/emitter open and -225.0 collector to emitter voltage/static/base open and -6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between -1.00 amperes source cutoff current and -2.00 amperes source cutoff current **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain

environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Specification Data:

81349-mil-s-19500/461 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig: